## INA6006AC1

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE

## **DESCRIPTION**

INA6006AC1 is a silicon PNP transistor.

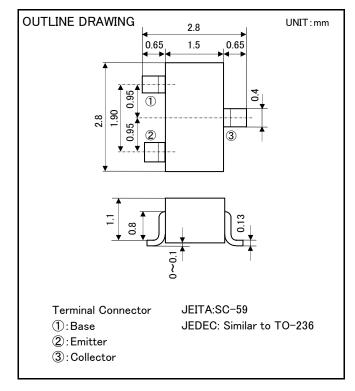
It is designed with high voltage.

## **FEATURE**

- ·Small package for easy mounting.
- •High voltage  $V_{CEO} = -150V$
- •Low voltage VCE(sat) = -0.5V(MAX)
- •Complementary : INC6006AC1

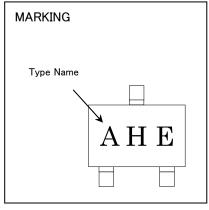
## **APPLICATION**

High voltage switching.



## MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING	UNIT	
V <sub>CBO</sub>	Collector to Base voltage	-160	٧	
$V_{EBO}$	Emitter to Base voltage	-5	٧	
$V_{\text{CEO}}$	Collector to Emitter voltage	-150	٧	
I <sub>CM</sub>	Peak collector current	-200	mA	
I c	Collector current	-100	mA	
P <sub>c</sub>	Collector dissipation(Ta=25°C)	200	mW	
		500(*)		
T <sub>j</sub>	Junction temperature	+150	°C	
$T_{stg}$	Storage temperature	-55 <b>~</b> +150	°C	

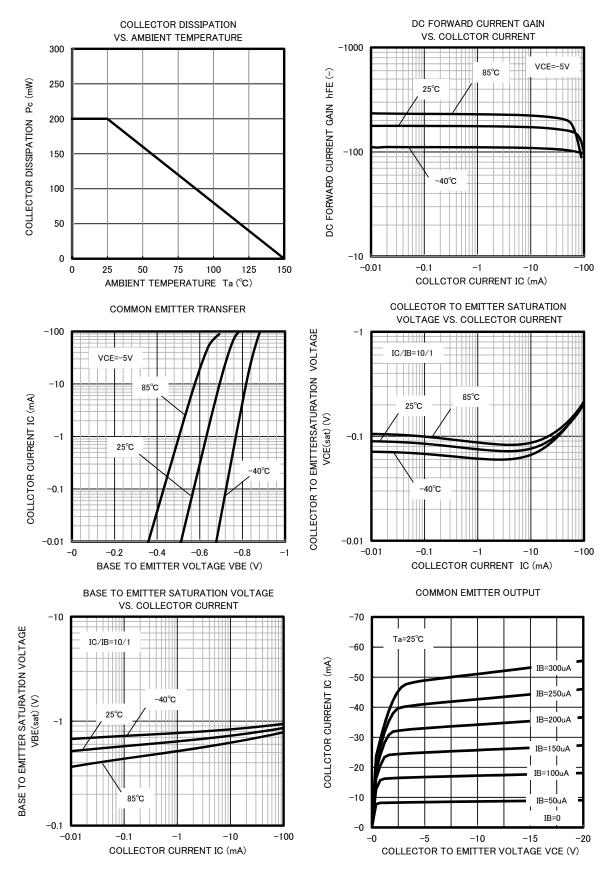


## ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			LINIT
			MIN	TYP	MAX	UNIT
V <sub>(BR)CBO</sub>	C to B break down voltage	$I_c=-100 \mu A$ , $I_E=0mA$	-160	-	-	٧
V <sub>(BR)EBO</sub>	E to B break down voltage	$I_{E}$ =-10 $\mu$ A, $I_{C}$ =0mA	-5	-	-	V
V <sub>(BR)CEO</sub>	C to E break down voltage	I <sub>c</sub> =-1mA, R <sub>BE</sub> =∞	-150	-	-	٧
I <sub>CBO</sub>	Collector cut off current	V <sub>CB</sub> =-120V, I <sub>E</sub> =0mA	-	-	-100	nA
I <sub>EBO</sub>	Emitter cut off current	$V_{EB}$ =-3V, I $_{C}$ =0mA	-	-	-100	nA
hFE1	DC forward current gain1	VCE=-5V, I <sub>c</sub> =-1mA	45	-	-	-
hFE2	DC forward current gain2	VCE=-5V, I <sub>c</sub> =-10mA	90	-	270	-
hFE3	DC forward current gain3	VCE=-5V, I <sub>c</sub> =-50mA	45	-	-	-
VCE(sat)1	C to E saturation voltage1	I <sub>c</sub> =-10mA, I <sub>B</sub> =-1mA	-	-	-0.2	٧
VCE(sat)2	C to E saturation voltage2	$I_{c}$ =-50mA, $I_{B}$ =-5mA	_	-	-0.5	٧
VBE(sat)1	B to E saturation voltage1	I <sub>c</sub> =-10mA, I <sub>B</sub> =-1mA	-	-	-1.0	٧
VBE(sat)2	B to E saturation voltage2	I <sub>c</sub> =-50mA, I <sub>B</sub> =-5mA	-	-	-1.0	٧
VBE(on)	B to E on voltage	VCE=-5V, I <sub>c</sub> =-10mA	-	-	-0.77	٧
fT	Gain bandwidth product	VCE=-10V, I <sub>E</sub> =10mA	100	-	300	MHz
Cob	Collector output capacitance	VCB=-10V, I <sub>E</sub> =0mA, f=1MHz	-	2.8	6	pF

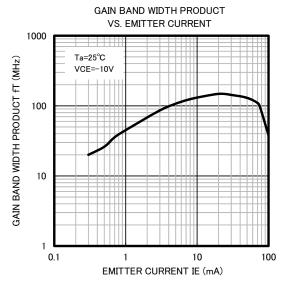
<sup>\*</sup>Mounted on glass epoxy board(46mm × 19mm × 1mm)

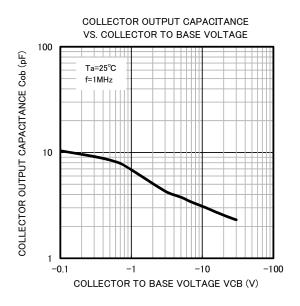
#### TYPICIAL CHARACTERISTICS

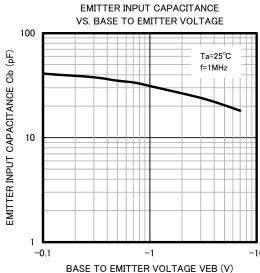


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